

Maksim Gavrikov

List of Publications by Year in descending order

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15
papers

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2682572

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times ranked

9
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|--|-----|-----------|
| 1 | Studying the influence of substrate conductivity on the optoelectronic properties of quantum dots langmuir monolayer. <i>Materials Research Express</i> , 2018, 5, 045050. | 1.6 | 2 |
| 2 | Peculiarities of Electron Transport and Photoconductivity in a Layer of Lead Sulfide Nanoparticles. <i>Technical Physics Letters</i> , 2019, 45, 370-373. | 0.7 | 2 |
| 3 | Study of the Electrophysical Properties of Colloidal Indium Antimonide Quantum Dots. <i>Technical Physics Letters</i> , 2020, 46, 339-341. | 0.7 | 2 |
| 4 | Multigrain Structures of the Semiconductor Nanoparticles. <i>Nano - I Mikrosistemnaya Tekhnika</i> , 2019, 21, 397-405. | 0.1 | 2 |
| 5 | Single-Electron Emissionâ€“Injection Transport in a Microstructure with Colloidal Quantum Dots of Narrow-Gap Semiconductors. <i>Semiconductors</i> , 2021, 55, 470-475. | 0.5 | 2 |
| 6 | Single-Electron Transport in Colloidal Quantum Dots of Narrow-Gap Semiconductors. <i>Technical Physics Letters</i> , 2020, 46, 881-884. | 0.7 | 1 |
| 7 | Shape Effect on the Electrical Properties of Indium-Antimonide Quantum Dots. <i>Semiconductors</i> , 2021, 55, 315-318. | 0.5 | 1 |
| 8 | Methodology of analyzing the CdSe semiconductor quantum dots parameters. <i>Nanosystems: Physics, Chemistry, Mathematics</i> , 2018, , 464-467. | 0.4 | 1 |
| 9 | Methodology of analyzing the InSb semiconductor quantum dots parameters. <i>Nanosystems: Physics, Chemistry, Mathematics</i> , 2019, 10, 720-724. | 0.4 | 1 |
| 10 | Thermionic Emission from Indium Antimonide Quantum Dots. <i>Technical Physics Letters</i> , 2021, 47, 385-387. | 0.7 | 1 |
| 11 | Electron Emission Properties of Submicron Semiconductor Particles. <i>Technical Physics Letters</i> , 2018, 44, 1230-1233. | 0.7 | 0 |
| 12 | Investigation of indium antimonide nanoparticles, obtained by the method of liquid chemical etching. <i>Journal of Physics: Conference Series</i> , 2019, 1410, 012048. | 0.4 | 0 |
| 13 | Features of the Conduction Mechanism through an Indium Antimonide Quantum Dot in the Analysis of Tunneling Current-Voltage Characteristics. <i>Nano Hybrids and Composites</i> , 0, 28, 130-135. | 0.8 | 0 |
| 14 | Analysis of the energy spectrum of indium antimonide quantum dots with temperature changes. <i>Nanosystems: Physics, Chemistry, Mathematics</i> , 2021, 12, 113-117. | 0.4 | 0 |
| 15 | Method for analyzing the electrophysical properties of semiconductor quantum dots. <i>Journal of Physics: Conference Series</i> , 2020, 1695, 012200. | 0.4 | 0 |